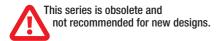
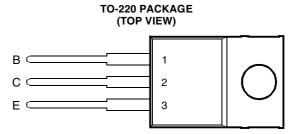


- Designed for Complementary Use with BDW64, BDW64A, BDW64B, BDW64C and BDW64D
- 60 W at 25°C Case Temperature
- 6 A Continuous Collector Current
- Minimum h<sub>FE</sub> of 750 at 3V, 2 A





Pin 2 is in electrical contact with the mounting base.

MDTRACA

# absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT	
	BDW63		45		
	BDW63A		60		
Collector-base voltage (I <sub>E</sub> = 0)	BDW63B	V <sub>CBO</sub>	80	V	
	BDW63C		100		
	BDW63D		120		
	BDW63		45		
	BDW63A		60		
Collector-emitter voltage (I <sub>B</sub> = 0) (see Note 1)	BDW63B	$V_{CEO}$	80	V	
	BDW63C		100		
	BDW63D		120		
Emitter-base voltage		V <sub>EB</sub>	5	V	
Continuous collector current		I <sub>C</sub>	6	Α	
Continuous base current		I <sub>B</sub>	0.1	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			60	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note	3)	P <sub>tot</sub>	2	W	
Unclamped inductive load energy (see Note 4)		½Ll <sub>C</sub> <sup>2</sup>	50	mJ	
Operating junction temperature range		Tj	-65 to +150	°C	
Operating temperature range		T <sub>stg</sub>	-65 to +150	°C	
Operating free-air temperature range			T <sub>A</sub> -65 to +150		

NOTES: 1. These values apply when the base-emitter diode is open circuited.

- 2. Derate linearly to 150°C case temperature at the rate of 0.48 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH,  $I_{B(on)}$  = 5 mA,  $R_{BE}$  = 100  $\Omega$ ,  $V_{BE(off)}$  = 0,  $R_S$  = 0.1  $\Omega$ ,  $V_{CC}$  = 20 V.



# electrical characteristics at 25°C case temperature (unless otherwise noted)

	PARAMETER		TES	T CONDITIONS		MIN	TYP	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 30 mA	I <sub>B</sub> = 0	(see Note 5)	BDW63 BDW63A BDW63B BDW63C BDW63D	45 60 80 100 120			V
I <sub>CEO</sub>	Collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 30 \text{ V}$ $V_{CE} = 40 \text{ V}$ $V_{CE} = 50 \text{ V}$ $V_{CE} = 60 \text{ V}$	$I_{B} = 0$		BDW63 BDW63A BDW63B BDW63C BDW63D			0.5 0.5 0.5 0.5 0.5	mA
I <sub>CBO</sub>	Collector cut-off current	V <sub>CB</sub> = 80 V	E = 0  E = 0	$T_{C} = 150^{\circ}\text{C}$	BDW63 BDW63A BDW63B BDW63C BDW63D BDW63 BDW63A BDW63B BDW63C BDW63D			0.2 0.2 0.2 0.2 0.2 5 5 5 5	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 5 V	I <sub>C</sub> = 0					2	mA
h <sub>FE</sub>	Forward current transfer ratio	$V_{CE} = 3 V$ $V_{CE} = 3 V$	$I_C = 2 A$ $I_C = 6 A$	(see Notes 5 and 6)		750 100		20000	
V <sub>BE(on)</sub>	Base-emitter voltage	V <sub>CE</sub> = 3 V	$I_C = 2 A$	(see Notes 5 and 6)				2.5	V
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	$I_B = 12 \text{ mA}$ $I_B = 60 \text{ mA}$	I <sub>C</sub> = 2 A I <sub>C</sub> = 6 A	(see Notes 5 and 6)				2.5 4	V
V <sub>EC</sub>	Parallel diode forward voltage	I <sub>E</sub> = 6 A	I <sub>B</sub> = 0					3.5	V

NOTES: 5. These parameters must be measured using pulse techniques,  $t_0 = 300 \mu s$ , duty cycle  $\leq 2\%$ .

# thermal characteristics

	PARAMETER			MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			2.08	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

# resistive-load-switching characteristics at 25°C case temperature

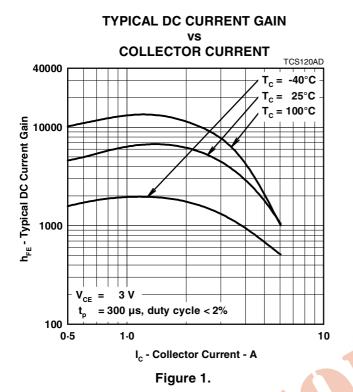
Ī		PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
Ī	t <sub>on</sub>	Turn-on time	I <sub>C</sub> = 3 A	I <sub>B(on)</sub> = 12 mA	$I_{B(off)} = -12 \text{ mA}$		1		μs
Ī	t <sub>off</sub>	Turn-off time	$V_{BE(off)} = -4.5 \text{ V}$	$R_L = 10 \Omega$	$t_p = 20 \ \mu s, \ dc \le 2\%$		5		μs

<sup>&</sup>lt;sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

<sup>6.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.



# TYPICAL CHARACTERISTICS



2.0 = 300 μs, duty cycle < 2%  $I_B = I_C / 100$ 

**COLLECTOR-EMITTER SATURATION VOLTAGE** 

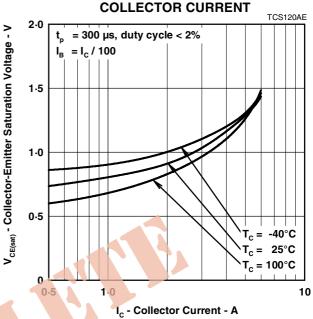
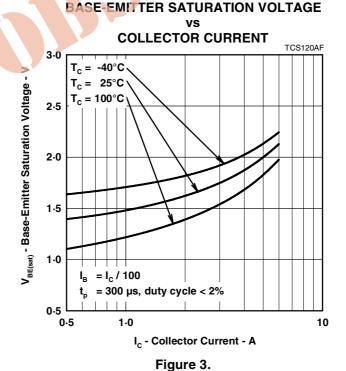
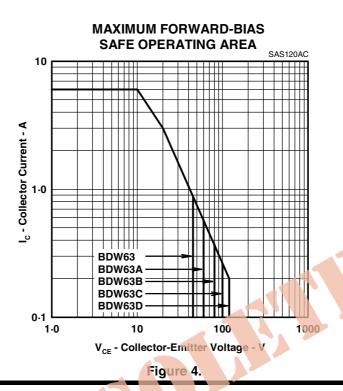


Figure 2.



## PRODUCT INFORMATION

# **MAXIMUM SAFE OPERATING REGIONS**



# THERMAL INFORMATION

**MAXIMUM POWER DISSIPATION** 

# CASE TEMPERATURE TIS120AB N - 100 N - 100 TIS120AB TIS120AB TIS120AB

0

25

50

75

 $T_c$  - Case Temperature - °C Figure 5.

PRODUCT INFORMATION

125

150

100